NSN 5961-01-462-3435

A110a0

Mil-std (military Standard):

Mil-prf-19500 spec.

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-462-3435 **Inclosure Material:** Ceramic and metal **Overall Length:** 0.200 inches **Overall Height:** 0.103 inches Overall Width: 0.103 inches **Mounting Method:** Press fit **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 150.0 working peak reverse voltage **Current Rating Per Characteristic:** 35.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Test Data Document:** 81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 case **Specification Data:** 81349-mil-prf-19500/477 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: